

#### Vishay High Power Products

## FlipKY<sup>®</sup> Chip Scale Package Schottky Barrier Rectifier, 0.75 A



0.75 A

30 V

# • Ultra low V<sub>F</sub> t

- Ultra low V<sub>F</sub> to footprint area
- Very low profile (< 0.6 mm)</li>
- Low thermal resistance
- Supplied tested and on tape and reel

#### APPLICATIONS

- Reverse polarity protection
- · Current steering
- Freewheeling
- Flyback
- Oring

#### DESCRIPTION

Vishay's FlipKY<sup>®</sup> product family utilizes wafer level chip scale packaging to deliver Schottky diodes with the lowest V<sub>F</sub> to PCB footprint area in industry. The three pad 0.9 mm x 1.2 mm devices can deliver up to 0.75 A and occupy only 1.08 mm<sup>2</sup> of board space. The anode and cathode connections are made through solder bump pads on one side of the silicon enabling designers to strategically place the diodes on the PCB. This design not only minimizes board space but also reduces thermal resistance and inductance, which can improve overall circuit efficiency.

Typical applications include hand-held, portable equipment such as cell phones, MP3 players, bluetooth, GPS, PDAs, and portable hard disk drives where space savings and performance are crucial.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	MAX.	UNITS		
V <sub>RRM</sub>		30	V		
I <sub>F(AV)</sub>	Rectangular waveform	0.75	А		
I <sub>FSM</sub>		190	A		
V <sub>F</sub>	0.75 Apk, T <sub>J</sub> = 125 °C	0.37	V		
TJ		- 55 to 150	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	FCSP0730TR	UNITS	
Maximum DC reverse voltage	V <sub>R</sub>	30	V	
Maximum working peak reverse voltage	V <sub>RWM</sub>	30	v	

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**PRODUCT SUMMARY** 

I<sub>F(AV)</sub>

 $V_{R}$ 



# FCSP0730TR



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#### **FlipKY**® Chip Scale Package Schottky Barrier Rectifier, 0.75 A

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I <sub>F(AV)</sub>	50 % duty cycle at $T_{PCB}$ = 127 °C, rectangular waveform		0.75	
Maximum peak one cycle non-repetitive surge current at 25 °C	I <sub>FSM</sub>	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated V <sub>RRM</sub> applied	190	А
		10 ms sine or 6 ms rect. pulse		10	
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 2.0 A, L = 5.0 mH		5	mJ
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		0.5	А

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
Maximum forward voltage drop See fig. 1		0.75 A	T <sub>.1</sub> = 25 °C	0.43		
	V <sub>FM</sub> <sup>(1)</sup>	1.5 A	- 1j=25 C	0.50	0.54	v
	V FM ( )	0.75 A		0.37	v	
		1.5 A	– T <sub>J</sub> = 125 °C	0.43	0.47	1
Maximum reverse leakage current See fig. 2	I <sub>BM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	$V_{\rm B}$ = Rated V <sub>B</sub>	10 5	50	μA
	IRM (")	T <sub>J</sub> = 125 °C	$v_{\rm R} = naleu v_{\rm R}$		15	mA
Maximum junction capacitance	CT	$V_{\rm R}$ = 5 $V_{\rm DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		-	90	pF
Maximum voltage rate of charge	dV/dt	Rated V <sub>R</sub>		-	10 000	V/µs

Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

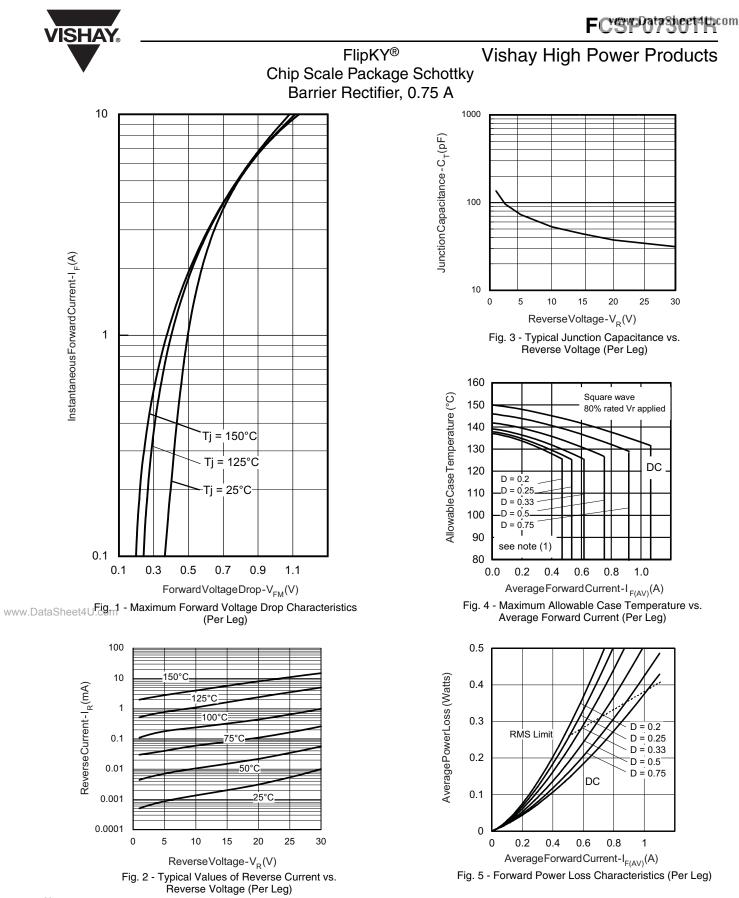
<b>THERMAL - MECHANICA</b>	THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and bataSneet40.com storage temperature range	$T_{J}$ <sup>(1)</sup> , $T_{Stg}$		- 55 to 150	°C	
Typical thermal resistance, junction to PCB	R <sub>thJL</sub> <sup>(2)</sup>	DC operation	35	°C/W	
Typical thermal resistance, junction to ambient	R <sub>thJA</sub>		150	0/10	

#### Notes

(1)

 $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink

<sup>(2)</sup> Mounted on minimum footprint PCB



#### Note

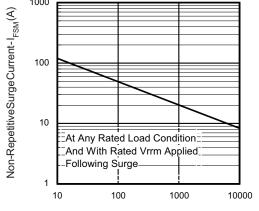
<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} \times I_{R} (1 - D); I_{R} at 80 \% V_{R} applied$ 

# FCSP0730TR

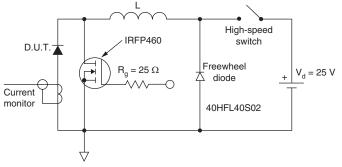






SquareWavePulseDuration- $t_p$ (microsec)

Fig. 6 - Maximum Non-Repetitive Surge Current (Per Leg)





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Dimensions	http://www.vishay.com/doc?95049
Part marking information	http://www.vishay.com/doc?95060
Packaging information	http://www.vishay.com/doc?95062



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